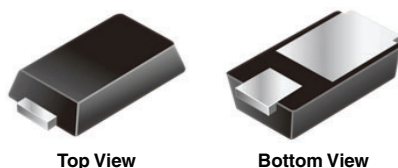


# Ultrafast Rectifier, 1 A FRED Pt®

## eSMP® Series



Top View

Bottom View

## MicroSMP (DO-219AD)

Anode  Cathode

## FEATURES

- Very low profile - typical height of 0.65 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## LINKS TO ADDITIONAL RESOURCES



3D Models

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	1 A
$V_R$	100 V, 200 V
$V_F$ at $I_F$	0.72 V
$t_{rr}$ (typ.)	33 ns
$I_{FSM}$	30 A
$T_J$ max.	175 °C
Package	MicroSMP (DO-219AD)
Circuit configuration	Single

## TYPICAL APPLICATIONS

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial and automotive applications.

## MECHANICAL DATA

**Case:** MicroSMP (DO-219AD)

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002, meets JESD 201 class 2 whisker test

**Polarity:** color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	$V_{RRM}$		100		V
			200		
Average rectified forward current	$I_{F(AV)}$	$T_M = 159\text{ °C}$	1		A
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25\text{ °C}$ , 10 ms sine pulse	30		
Operating junction and storage temperatures	$T_J, T_{Stg}$		-55 to +175		°C

ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100\text{ }\mu\text{A}$	100	-	-		V
			200				
Forward voltage	$V_F$	$I_F = 1\text{ A}$	-	0.88	0.97		
		$I_F = 1\text{ A}, T_J = 150\text{ °C}$	-	0.72	0.75		
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	-	1		$\mu\text{A}$
		$T_J = 150\text{ °C}, V_R = V_R$ rated	-	-	25		
Junction capacitance	$C_T$	$V_R = 200\text{ V}$	-	6	-		pF



DYNAMIC RECOVERY CHARACTERISTICS ( $T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1.0\text{ A}$ , $dI_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	33	-	ns
		$I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{rr} = 0.25\text{ A}$	-	-	23	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	13	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	18	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	1.8	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	2.7	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	11	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	23	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction to mount	R <sub>thJM</sub> <sup>(1)</sup>		-	16	20	°C/W
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Device mounted on FR4 PCB, 2 oz. standard footprint	-	160	-	
Approximate weight			0.006			g
Marking device	VS-1EQH01-M3	Case style MicroSMP (DO-219AD)	1H1			
	VS-1EQH02-M3		1H2			

**Note**

(1) Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

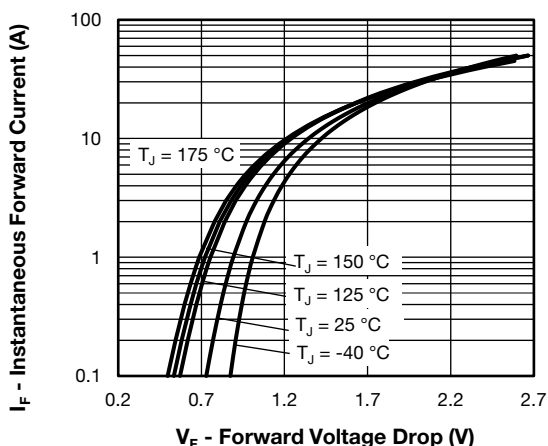


Fig. 1 - Typical Forward Voltage Drop Characteristics

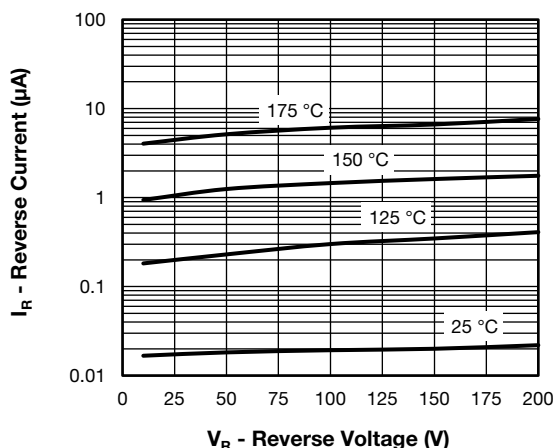


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

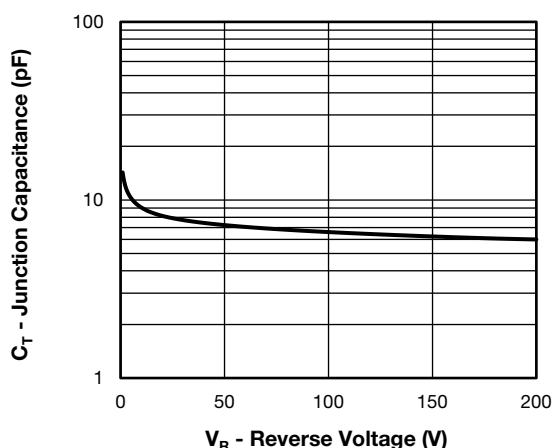


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

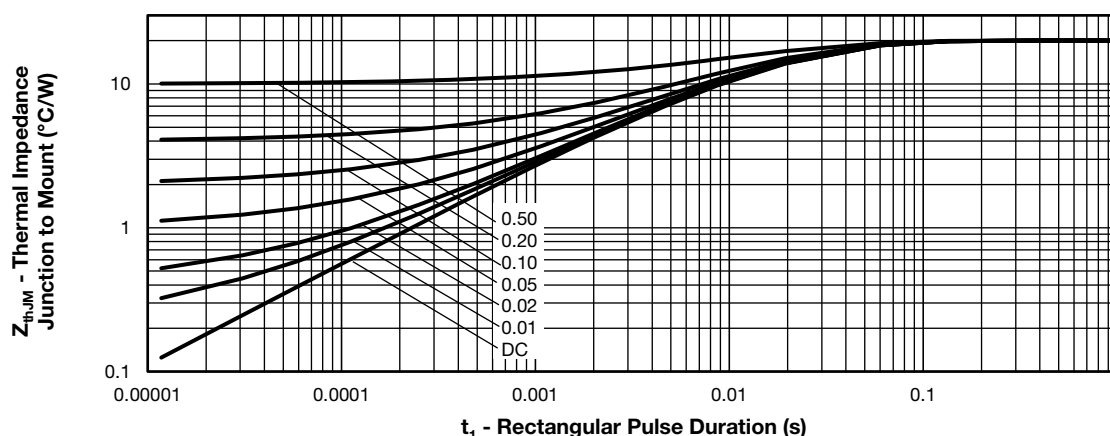


Fig. 4 - Maximum Transient Thermal Impedance, Junction to Mount

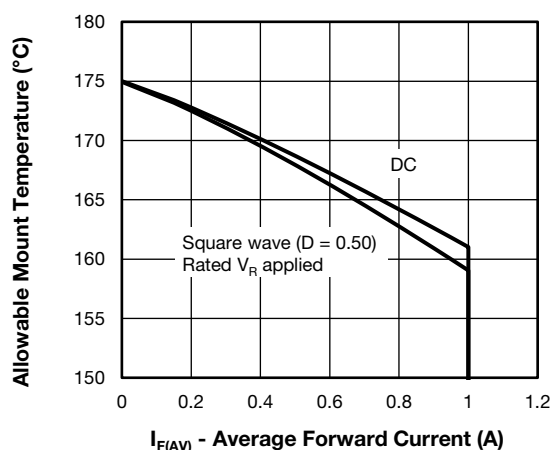


Fig. 5 - Maximum Allowable Mount Temperature vs. Average Forward Current

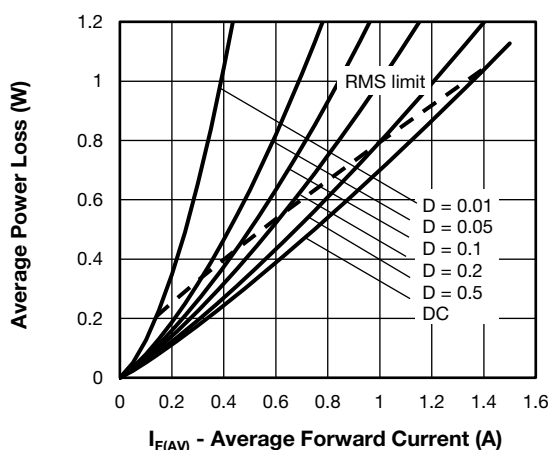


Fig. 6 - Forward Power Loss Characteristics

#### Note

Formula used:  $T_M = T_J - (P_d + P_{dREV}) \times R_{thJM}$ ;

$P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);

$P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

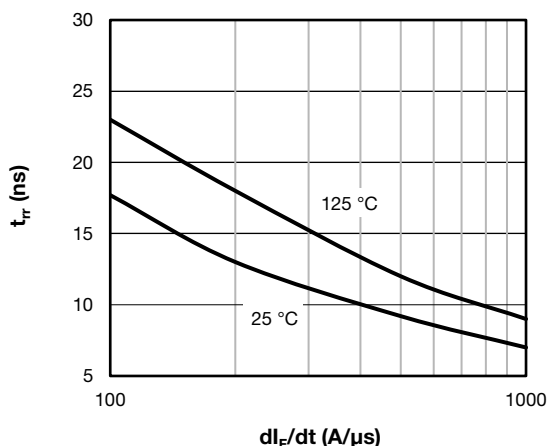
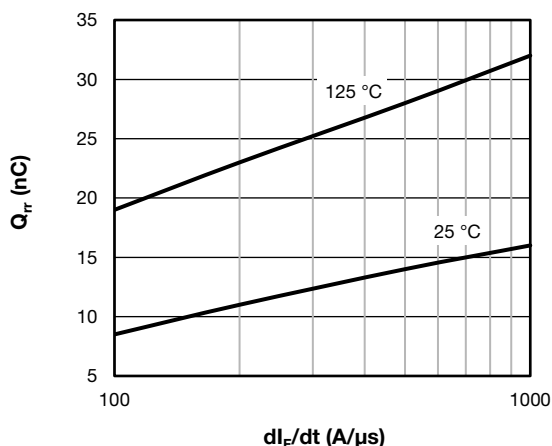
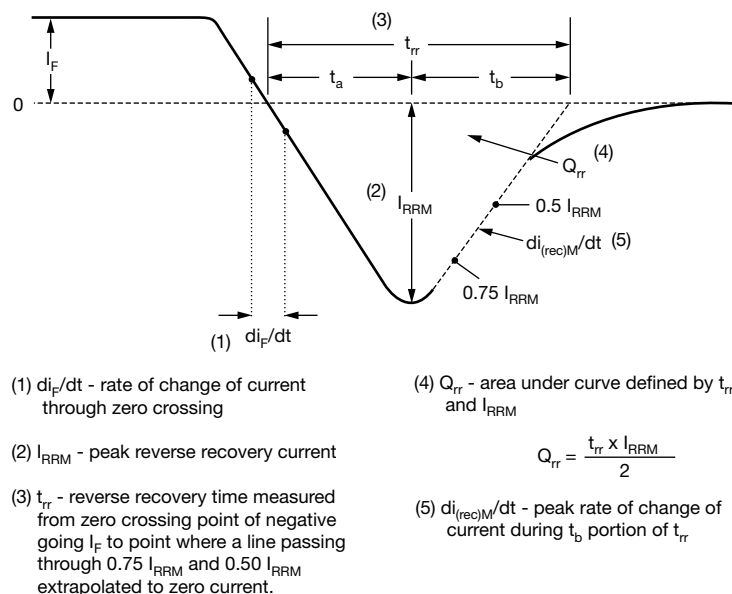

Fig. 7 - Typical Reverse Recovery Time vs.  $di_F/dt$ 

Fig. 8 - Typical Stored Charge vs.  $di_F/dt$ 


Fig. 9 - Reverse Recovery Waveform and Definitions

**ORDERING INFORMATION TABLE**

Device code	<b>VS-</b>	<b>1</b>	<b>E</b>	<b>Q</b>	<b>H</b>	<b>02</b>	<b>H</b>	<b>M3</b>
	1	2	3	4	5	6	7	8
	<b>1</b>	-	Vishay Semiconductors product					
	<b>2</b>	-	Current rating (1 = 1 A)					
	<b>3</b>	-	Circuit configuration: E = single diode					
	<b>4</b>	-	Q = MicroSMP package					
	<b>5</b>	-	Process type, H = ultrafast recovery					
	<b>6</b>	-	Voltage code (02 = 200 V)					
	<b>7</b>	-	H = AEC-Q101 qualified					
	<b>8</b>	-	M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free					

**ORDERING INFORMATION** (Example)

PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-1EQH01-M3/H	H	4500	7" diameter plastic tape and reel
VS-1EQH02-M3/H	H	4500	7" diameter plastic tape and reel

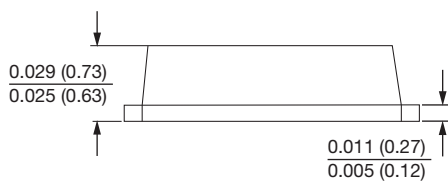
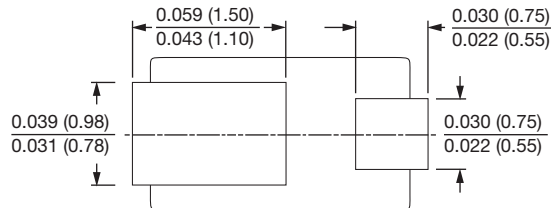
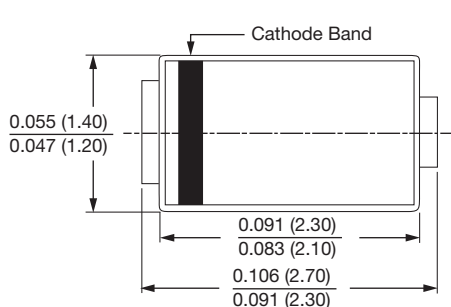
**LINKS TO RELATED DOCUMENTS**

Dimensions	<a href="http://www.vishay.com/doc?96591">www.vishay.com/doc?96591</a>
Part marking information	<a href="http://www.vishay.com/doc?96590">www.vishay.com/doc?96590</a>
Packaging information	<a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a>
SPIICE model	<a href="http://www.vishay.com/doc?96594">www.vishay.com/doc?96594</a>

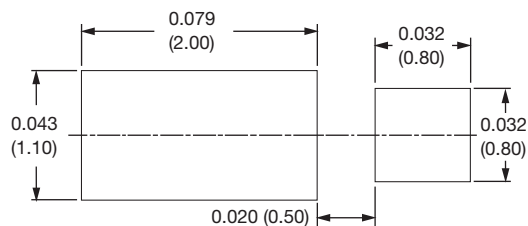


## MicroSMP (DO-219AD), FRED Pt®

**DIMENSIONS** in inches (millimeters)



**Mounting Pad Layout**





## Disclaimer

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